BAS19W- BAS21W SURFACE MOUNT FAST SWITCHING DIODE

Technical Data Green Products

Features

High Conductance

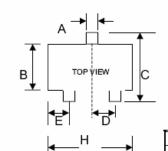
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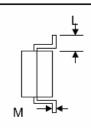
- Fast Switching
- Surface Mount Package Ideally Suited for Automatic Insertion
- For General Purpose and Switching
- Plastic Material UL Recognition Flammability Classification 94V-O
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

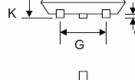
Mechanical Data

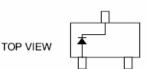
- Case: SOT-323, Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: See Diagram
- Weight: 0.006 grams (approx.)
- Mounting Position: Any
- Marking: BAS19W A8

BAS20W A80 BAS21W A82









| SOT-323 | | | | | | | | |
|---------|--------------|------|--------------|-------|--|--|--|--|
| Dim | Min | Max | Min | Max | | | | |
| Α | 0.30 | 0.40 | 0.012 | 0.016 | | | | |
| В | 1.15 | 1.35 | 0.045 | 0.053 | | | | |
| O | 2.00 | 2.20 | 0.079 | 0.087 | | | | |
| D | 0.65 Nominal | | 0.026Nominal | | | | | |
| Е | 0.30 | 0.40 | 0.012 | 0.016 | | | | |
| O | 1.20 | 1.40 | 0.047 | 0.055 | | | | |
| Н | 1.80 | 2.20 | 0.071 | 0.087 | | | | |
| J | | 0.10 | _ | 0.004 | | | | |
| Κ | 0.90 | 1.10 | 0.035 | 0.043 | | | | |
| Г | 0.25 | _ | 0.010 | _ | | | | |
| М | 0.05 | 0.15 | 0.002 | 0.006 | | | | |
| | In mm | | In inch | | | | | |

Maximum Ratings @TA=25°C unless otherwise specified

| Characteristic | | BAS19W | BAS20W | BAS21W | Unit |
|----------------------------------------------------------------------------------------|--------------------|-------------|--------|--------|------|
| Non-Repetitive Peak Reverse Voltage | VRM | 120 | 200 | 250 | ٧ |
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | Vrrm Vrwm Vr | 100 | 150 | 200 | ٧ |
| Forward Continuous Current (Note 1) | lF | 400 | | | mA |
| Average Rectified Output Current (Note 1) | lo | 200 | | | mA |
| Peak Forward Surge Current (Note 1) @ t = 1.0μs | IFSM | 2.5 | | | Α |
| Power Dissipation (Note 1) | Pd | 200 | | | mW |
| Typical Thermal Resistance, Junction to Ambient Air (Note 1) | R_{θ} JA | 625 | | | K/W |
| Operating and Storage Temperature Range | Tj, Tstg | -65 to +150 | | | °C |

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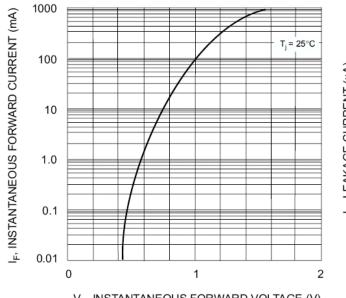
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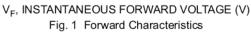
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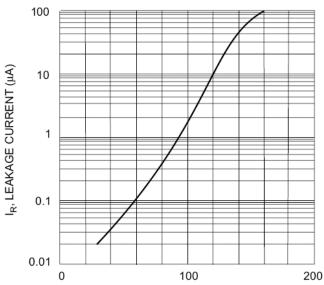
Electrical Characteristics @TA=25°C unless otherwise specified

| Characteristic | Symbol | Min | Max | Unit | Test Condition |
|-------------------------|--------|-----|-------------|------|-------------------------------------------------------------|
| Forward Voltage | VF | _ | 1.0 1.25 | ٧ | @ IF = 100mA @ IF = 200mA |
| Reverse Leakage Current | lR | _ | 100 | nA | @ Rated DC Blocking Voltage |
| Junction Capacitance | Cj | _ | 5.0 | pF | V _R = 0V, f = 1.0MHz |
| Reverse Recovery Time | trr | _ | 50 | nS | IF = IR = 30 mA, IRR = 0.1 x IR, RL = 100 Ω |

Note: 1. Device mounted on fiberglass substrate 40 x 40 x 1.5mm.







 $\label{eq:tj} \textbf{T}_{j}, \, \text{JUNCTION TEMPERATURE (°C)} \\ \text{Fig. 2 Leakage Current vs Junction Temperature}$

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